

Electrically Conductive, Silver Epoxy

Number of Components:	Тwo	Minimum Bond Line Cure Schedule*:	
Mix Ratio By Weight:	1:1	180°C	1 Hour
Specific Gravity:		150°C	2 Hours
Part A	2.44		
Part B	3.07		
Pot Life:	3.5 Days		
Shelf Life:	One year at room temperature	ntants of asch container (A	8 P) thoroughly before mixing th

Note: Container(s) should be kept closed when not in use. For filled systems, mix contents of each container (A & B) thoroughly before mixing the two together. \*Please see Applications Note available on our website.

## **Product Description:**

EPO-TEK<sup>®</sup> H20E-175 is a two component epoxy designed for semiconductor die-attach. It is a higher Tg version of EPO-TEK<sup>®</sup> H20E. It was designed to be used in semiconductor / JEDEC packaging, microelectronic packaging of hybrids, as well as high temperature devices and assembly.

## EPO-TEK<sup>®</sup> H20E-175 Advantages & Application Notes:

- Thixotropic paste-like rheology allows for high speed dispensing and screen printing operations. It can also be applied by hand techniques using spatula, toothpick, or stamping chuck.
- Suggested for Rf/Microwave device packaging found in military, commercial, aerospace and cockpit, and industrial (down-hole petrochemical) circuits.
- > 3 day pot-life allows for mass production yielding low waste.

**Typical Properties:** (To be used as a guide only, not as a specification. Data below is not guaranteed. Different batches, conditions and applications yield differing results; Cure condition: 180°C/1 hour; \* denotes test on lot acceptance basis)

Physical Properties:			
*Color: Part A: Silver Part B: Silver	Weight Loss:		
*Consistency: Smooth thixotropic paste	@ 200°C: 0.05%		
*Viscosity (@ 100 RPM/23°C): 2,800 – 3,800 cPs	@ 250°C: 0.11%		
Thixotropic Index: 3.1	@ <b>300°C:</b> 0.25%		
*Glass Transition Temp.(Tg): ≥ 85°C (Dynamic Cure	Operating Temp:		
20—250°C /ISO 25 Min; Ramp -10—250°C @ 20°C/Min)	Continuous: - 55°C to 250°C		
Coefficient of Thermal Expansion (CTE):	Intermittent: - 55°C to 350°C		
Below Tg: 20 x 10 <sup>-6</sup> in/in/°C	Storage Modulus @ 23°C: 628,212 psi		
<b>Above Tg:</b> 88 x 10 <sup>-6</sup> in/in/°C	lons: Cl		
Shore D Hardness: 70	Na <sup>+</sup>		
Lap Shear Strength @ 23°C: 1,292 psi	$NH_4^+$		
Die Shear Strength @ 23°C: ≥ 10 Kg / 3,400 psi	K <sup>+</sup>		
Degradation Temp. (TGA): 450°C	*Particle Size: ≤ 45 Microns		
Electrical Properties:			
*Volume Resistivity @ 23°C: ≤ 0.0004 Ohm-cm			
Thermal Properties:			
Thermal Conductivity: 2.04 W/mK			

## EPOXY TECHNOLOGY, INC.

14 Fortune Drive, Billerica, MA 01821-3972 **Phone**: 978.667.3805 **Fax**: 978.663.9782 www.EPOTEK.com

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